

# NXS0108

Dual supply translating transceiver; open drain;  
auto direction sensing

Rev. 1 — 15 September 2020

Product data sheet

## 1. General description

The NXS0108 is an 8-bit, dual supply translating transceiver with auto direction sensing, that enables bidirectional voltage level translation. It features two 8-bit input-output ports (An and Bn), one output enable input (OE) and two supply pins ( $V_{CC(A)}$  and  $V_{CC(B)}$ ).  $V_{CC(A)}$  can be supplied at any voltage between 1.2 V and 3.6 V and  $V_{CC(B)}$  can be supplied at any voltage between 1.65 V and 5.5 V, making the device suitable for translating between any of the voltage nodes (1.2 V, 1.8 V, 2.5 V, 3.3 V and 5.0 V). Pins An and OE are referenced to  $V_{CC(A)}$  and pins Bn are referenced to  $V_{CC(B)}$ . A LOW level at pin OE causes the outputs to assume a high-impedance OFF-state. This device is fully specified for partial power-down applications using  $I_{OFF}$ . The  $I_{OFF}$  circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

## 2. Features and benefits

- Wide supply voltage range:
  - $V_{CC(A)}$ : 1.2 V to 3.6 V and  $V_{CC(B)}$ : 1.65 V to 5.5 V
- Maximum data rates:
  - Push-pull: 110 Mbps
- $I_{OFF}$  circuitry provides partial Power-down mode operation
- Inputs accept voltages up to 5.5 V
- ESD protection:
  - HBM JESD22-A114E Class 2 exceeds 2.5 kV for A port
  - HBM JESD22-A114E Class 3B exceeds 15 kV for B port
  - CDM JESD22-C101E exceeds 1.5 kV
  - IEC61000-4-2 contact discharge exceeds 8 kV for B port
- Latch-up performance exceeds 100 mA per JESD 78B Class II
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

## 3. Applications

- Desktop PC
- Handset
- Smartphone
- Tablet

## 4. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
NXS0108PW	-40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20 leads; body width 4.4 mm	SOT360-1
NXS0108BQ	-40 °C to +125 °C	DHVQFN20	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 × 4.5 × 0.85 mm	SOT764-1

### 5. Functional diagram

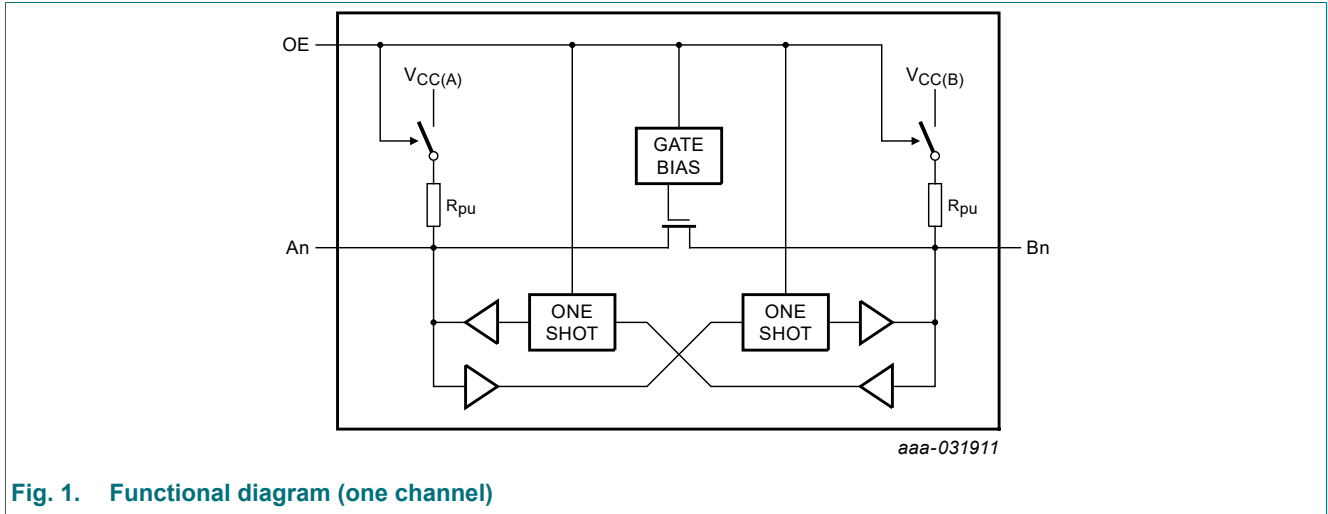


Fig. 1. Functional diagram (one channel)

### 6. Pinning information

#### 6.1. Pinning

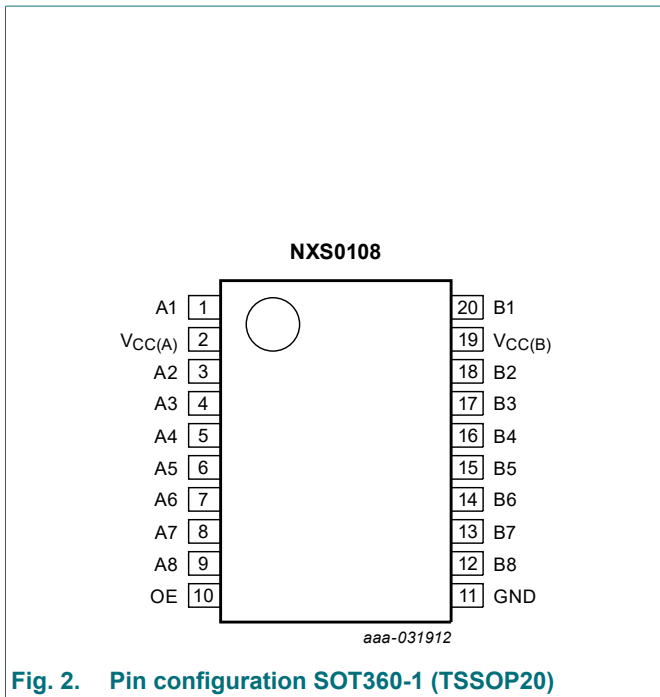


Fig. 2. Pin configuration SOT360-1 (TSSOP20)

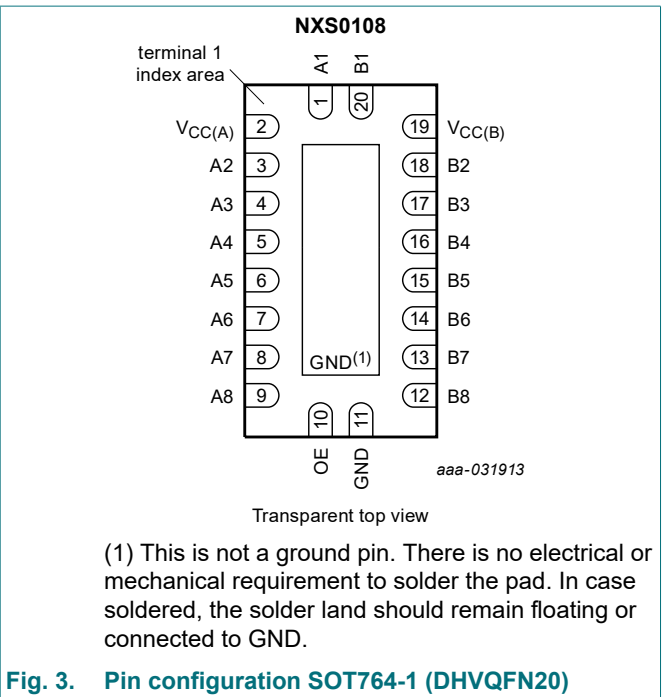


Fig. 3. Pin configuration SOT764-1 (DHVQFN20)

## 6.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
A1, A2, A3, A4, A5, A6, A7, A8	1, 3, 4, 5, 6, 7, 8, 9	data input or output (referenced to $V_{CC(A)}$ )
$V_{CC(A)}$	2	supply voltage A
OE	10	output enable input (active HIGH; referenced to $V_{CC(A)}$ )
GND	11	ground (0 V)
B1, B2, B3, B4, B5, B6, B7, B8	20, 18, 17, 16, 15, 14, 13, 12	data input or output (referenced to $V_{CC(B)}$ )
$V_{CC(B)}$	19	supply voltage B

## 7. Functional description

Table 3. Function table

*H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.*

Supply voltage		Input	Input/output	
$V_{CC(A)}$ [1]	$V_{CC(B)}$	OE	A	B
1.2 V to 3.6 V	1.65 V to 5.5 V	L	Z	Z
1.2 V to 3.6 V	1.65 V to 5.5 V	H	input or output	output or input
GND	1.65 V to 5.5 V	X	Z	Z
1.2 V to 3.6 V	GND	X	Z	Z

[1]  $V_{CC(A)}$  must be less than or equal to  $V_{CC(B)}$ .

## 8. Limiting values

Table 4. Limiting values

*In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).*

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC(A)}$	supply voltage A		-0.5	+6.5	V
$V_{CC(B)}$	supply voltage B		-0.5	+6.5	V
$V_I$	input voltage	OE [1]	-0.5	+6.5	V
		An, Bn; Power-down or 3-state mode [1]	-0.5	+6.5	V
		An, Bn; Active mode [1] [2] [3]	-0.5	$V_{CCI} + 0.5$	V
$V_O$	output voltage	An, Bn; Power-down or 3-state mode [1]	-0.5	+6.5	V
		An, Bn; Active mode [1] [3] [4]	-0.5	$V_{CCO} + 0.5$	V

## Dual supply translating transceiver; open drain; auto direction sensing

Symbol	Parameter	Conditions	Min	Max	Unit
$I_{IK}$	input clamping current	$V_I < 0\text{ V}$	-50	-	mA
$I_{OK}$	output clamping current	$V_O < 0\text{ V}$	-50	-	mA
$I_O$	output current	$V_O = 0\text{ V}$ to $V_{CCO}$ [4]	-	$\pm 50$	mA
$I_{CC}$	supply current	$I_{CC(A)}$ or $I_{CC(B)}$	-	100	mA
$I_{GND}$	ground current		-100	-	mA
$T_{stg}$	storage temperature		-65	+150	°C
$P_{tot}$	total power dissipation	$T_{amb} = -40\text{ °C}$ to $+125\text{ °C}$ [5]	-	500	mW

[1] The minimum input and minimum output voltage ratings may be exceeded if the input and output current ratings are observed.

[2]  $V_{CCI}$  is the supply voltage associated with the input.

[3]  $V_{CCI} + 0.5\text{ V}$  or  $V_{CCO} + 0.5\text{ V}$  should not exceed 6.5 V.

[4]  $V_{CCO}$  is the supply voltage associated with the output.

[5] For SOT360-1 (TSSOP20) package:  $P_{tot}$  derates linearly with 10.0 mW/K above 100 °C.  
For SOT764-1 (DHVQFN20) package:  $P_{tot}$  derates linearly with 12.9 mW/K above 111 °C.

## 9. Recommended operating conditions

Table 5. Recommended operating conditions [1] [2]

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC(A)}$	supply voltage A		1.2	3.6	V
$V_{CC(B)}$	supply voltage B		1.65	5.5	V
$V_I$	input voltage	OE	0	5.5	V
		Power-down or 3-state mode			
		An	0	3.6	V
		Bn	0	5.5	V
		Active mode			
	An, Bn	[3]	0	$V_{CCI}$	V
$V_O$	output voltage	Power-down or 3-state mode			
		An	0	3.6	V
		Bn	0	5.5	V
		Active mode			
		An, Bn	[4]	0	$V_{CCO}$
$T_{amb}$	ambient temperature		-40	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	A or B port; push-pull driving			
		$V_{CC(A)} = 1.2\text{ V}$ to $3.6\text{ V}$ ; $V_{CC(B)} = 1.65\text{ V}$ to $5.5\text{ V}$	-	10	ns/V
		OE input			
		$V_{CC(A)} = 1.2\text{ V}$ to $3.6\text{ V}$ ; $V_{CC(B)} = 1.65\text{ V}$ to $5.5\text{ V}$	-	10	ns/V

[1] The A and B sides of an unused I/O pair must be held in the same state, both at  $V_{CCI}$  or both at GND.

[2]  $V_{CC(A)}$  must be less than or equal to  $V_{CC(B)}$ .

[3]  $V_{CCI}$  is the supply voltage associated with the input.

[4]  $V_{CCO}$  is the supply voltage associated with the output.

## 10. Static characteristics

**Table 6. Typical static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $T_{amb} = 25\text{ }^{\circ}\text{C}$ . [1]

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
$V_{OL}$	LOW-level output voltage	A port; $V_I \leq 0.15\text{ V}$ ; $V_{CC(B)} = 1.65\text{ V to }5.5\text{ V}$ ; $V_{CC(A)} = 1.2\text{ V}$ ; $I_O = -135\text{ }\mu\text{A}$	-	0.25	-	V	
$I_I$	input leakage current	OE input; $V_I = 0\text{ V to }3.6\text{ V}$ ; $V_{CC(A)} = 1.2\text{ V to }3.6\text{ V}$ ; $V_{CC(B)} = 1.65\text{ V to }5.5\text{ V}$	-	-	$\pm 1$	$\mu\text{A}$	
$I_{OZ}$	OFF-state output current	A or B port; $V_O = 0\text{ V or }V_{CCO}$ ; $V_{CC(A)} = 1.2\text{ V to }3.6\text{ V}$ ; $V_{CC(B)} = 1.65\text{ V to }5.5\text{ V}$ [2]	-	-	$\pm 1$	$\mu\text{A}$	
$I_{OFF}$	power-off leakage current	A port; $V_I$ or $V_O = 0\text{ V to }3.6\text{ V}$ ; $V_{CC(A)} = 0\text{ V}$ ; $V_{CC(B)} = 0\text{ V to }5.5\text{ V}$	-	-	$\pm 1$	$\mu\text{A}$	
		B port; $V_I$ or $V_O = 0\text{ V to }5.5\text{ V}$ ; $V_{CC(B)} = 0\text{ V}$ ; $V_{CC(A)} = 0\text{ V to }3.6\text{ V}$	-	-	$\pm 1$	$\mu\text{A}$	
$C_I$	input capacitance	OE input; $V_{CC(A)} = 3.3\text{ V}$ ; $V_{CC(B)} = 3.3\text{ V}$	-	2.6	-	pF	
$C_{I/O}$	input/output capacitance	A port; $V_{CC(A)} = 3.3\text{ V}$ ; $V_{CC(B)} = 3.3\text{ V}$					
		enabled	-	9	-	pF	
		disabled	-	5.2	-	pF	
		B port; $V_{CC(A)} = 3.3\text{ V}$ ; $V_{CC(B)} = 3.3\text{ V}$					
		enabled	-	10.5	-	pF	
disabled	-	9	-	pF			

[1]  $V_{CC(A)}$  must be less than or equal to  $V_{CC(B)}$ .

[2]  $V_{CCO}$  is the supply voltage associated with the output.

**Table 7. Typical supply current**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V);  $T_{amb} = 25\text{ }^{\circ}\text{C}$ .

$V_{CC(A)}$	$V_{CC(B)}$								Unit
	1.8 V		2.5 V		3.3 V		5.0 V		
	$I_{CC(A)}$	$I_{CC(B)}$	$I_{CC(A)}$	$I_{CC(B)}$	$I_{CC(A)}$	$I_{CC(B)}$	$I_{CC(A)}$	$I_{CC(B)}$	
1.2 V	0.1	0.3	0.1	0.9	0.1	1.9	0.1	5.6	$\mu\text{A}$
1.5 V	0.1	0.1	0.1	0.7	0.1	1.7	0.1	5	$\mu\text{A}$
1.8 V	0.1	0.1	0.1	0.5	0.1	1.5	0.1	4.6	$\mu\text{A}$
2.5 V	-	-	0.1	0.1	0.1	0.8	0.1	3.8	$\mu\text{A}$
3.3 V	-	-	-	-	0.1	0.1	0.1	2.8	$\mu\text{A}$

## Dual supply translating transceiver; open drain; auto direction sensing

Table 8. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).[1]

Symbol	Parameter	Conditions	-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Max	Min	Max	
V <sub>IH</sub>	HIGH-level input voltage	A port					
		V <sub>CC(A)</sub> = 1.2 V to 1.95 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V	V <sub>CC(A)</sub> - 0.2	-	V <sub>CC(A)</sub> - 0.2	-	V
		V <sub>CC(A)</sub> = 1.95 V to 3.6 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V	V <sub>CC(A)</sub> - 0.4	-	V <sub>CC(A)</sub> - 0.4	-	V
		B port					
		V <sub>CC(A)</sub> = 1.2 V to 3.6 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V	V <sub>CC(B)</sub> - 0.4	-	V <sub>CC(B)</sub> - 0.4	-	V
		OE input					
		V <sub>CC(A)</sub> = 1.2 V to 3.6 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V	0.65V <sub>CC(A)</sub>	-	0.65V <sub>CC(A)</sub>	-	V
V <sub>IL</sub>	LOW-level input voltage	A or B port					
		V <sub>CC(A)</sub> = 1.2 V to 3.6 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V	-	0.15	-	0.15	V
		OE input					
		V <sub>CC(A)</sub> = 1.2 V to 3.6 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V	-	0.35V <sub>CC(A)</sub>	-	0.35V <sub>CC(A)</sub>	V
V <sub>OH</sub>	HIGH-level output voltage	A port; I <sub>O</sub> = -20 μA; V <sub>I</sub> ≥ V <sub>CC(B)</sub> - 0.4 V					
		V <sub>CC(A)</sub> = 1.2 V to 3.6 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V	0.67V <sub>CC(A)</sub>	-	0.67V <sub>CC(A)</sub>	-	V
		B port; I <sub>O</sub> = -20 μA; V <sub>I</sub> ≥ V <sub>CC(A)</sub> - 0.2 V					
		V <sub>CC(A)</sub> = 1.2 V to 3.6 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V	0.67V <sub>CC(B)</sub>	-	0.67V <sub>CC(B)</sub>	-	V
V <sub>OL</sub>	LOW-level output voltage	A port; V <sub>I</sub> ≤ 0.15 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V					
		V <sub>CC(A)</sub> = 1.4 V; I <sub>O</sub> = -180 μA	-	0.4	-	0.4	V
		V <sub>CC(A)</sub> = 1.65 V; I <sub>O</sub> = -220 μA	-	0.4	-	0.4	V
		V <sub>CC(A)</sub> = 2.3 V; I <sub>O</sub> = -300 μA	-	0.4	-	0.4	V
		V <sub>CC(A)</sub> = 3.0 V; I <sub>O</sub> = -400 μA	-	0.55	-	0.55	V
		B port; V <sub>I</sub> ≤ 0.15 V; V <sub>CC(A)</sub> = 1.2 V to 3.6 V					
		V <sub>CC(B)</sub> = 1.65 V; I <sub>O</sub> = -220 μA	-	0.4	-	0.4	V
		V <sub>CC(B)</sub> = 2.3 V; I <sub>O</sub> = -300 μA	-	0.4	-	0.4	V
		V <sub>CC(B)</sub> = 3.0 V; I <sub>O</sub> = -400 μA	-	0.55	-	0.55	V
		V <sub>CC(B)</sub> = 4.5 V; I <sub>O</sub> = -620 μA	-	0.55	-	0.55	V
I <sub>I</sub>	input leakage current	OE input; V <sub>I</sub> = 0 V to 3.6 V; V <sub>CC(A)</sub> = 1.2 V to 3.6 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V	-	±2	-	±12	μA
I <sub>OZ</sub>	OFF-state output current	A or B port; V <sub>O</sub> = 0 V or V <sub>CCO</sub> ; V <sub>CC(A)</sub> = 1.2 V to 3.6 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V	[2]	±2	-	±12	μA
I <sub>OFF</sub>	power-off leakage current	A port; V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC(A)</sub> = 0 V; V <sub>CC(B)</sub> = 0 V to 5.5 V	-	±2	-	±12	μA
		B port; V <sub>I</sub> or V <sub>O</sub> = 0 V to 3.6 V; V <sub>CC(B)</sub> = 0 V; V <sub>CC(A)</sub> = 0 V to 5.5 V	-	±2	-	±12	μA

## Dual supply translating transceiver; open drain; auto direction sensing

Symbol	Parameter	Conditions	-40 °C to +85 °C		-40 °C to +125 °C		Unit
			Min	Max	Min	Max	
I <sub>CC</sub>	supply current	OE = 0 V or V <sub>CC(A)</sub> ; An, Bn open					
		I <sub>CC(A)</sub>					
		V <sub>CC(A)</sub> = 1.2 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V	-5	0.5	-5	1	μA
		V <sub>CC(A)</sub> = 1.5 V to 3.6 V; V <sub>CC(B)</sub> = 2.3 V to 5.5 V	-2	1.2	-2	2	μA
		V <sub>CC(A)</sub> = 3.6 V; V <sub>CC(B)</sub> = 0 V	-	1.0	-	2	μA
		V <sub>CC(A)</sub> = 0 V; V <sub>CC(B)</sub> = 5.5 V	-1	-	-1	-	μA
		I <sub>CC(B)</sub>					
		V <sub>CC(A)</sub> = 1.2 V; V <sub>CC(B)</sub> = 1.65 V to 5.5 V	-	22	-	60	μA
		V <sub>CC(A)</sub> = 1.5 V to 3.6 V; V <sub>CC(B)</sub> = 2.3 V to 5.5 V	-	20	-	20	μA
		V <sub>CC(A)</sub> = 3.6 V; V <sub>CC(B)</sub> = 0 V	-1	-	-1	-	μA
		V <sub>CC(A)</sub> = 0 V; V <sub>CC(B)</sub> = 5.5 V	-	2	-	12	μA
		I <sub>CC(A)</sub> + I <sub>CC(B)</sub>					
		V <sub>CC(A)</sub> = 1.2 V; V <sub>CC(B)</sub> = 2.3 V to 5.5 V	-	17	-	65	μA
		V <sub>CC(A)</sub> = 1.5 V to 3.6 V; V <sub>CC(B)</sub> = 2.3 V to 5.5 V	-	20	-	20	μA

[1] V<sub>CC(A)</sub> must be less than or equal to V<sub>CC(B)</sub>.

[2] V<sub>CCO</sub> is the supply voltage associated with the output.

## 11. Dynamic characteristics

**Table 9. Typical dynamic characteristics**

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 7; for waveforms see Fig. 4 and Fig. 6.

Symbol	Parameter	Conditions	V <sub>CC(B)</sub>				Unit
			1.8 V ± 0.15 V	2.5 V ± 0.2 V	3.3 V ± 0.3 V	5.0 V ± 0.5 V	
<b>V<sub>CC(A)</sub> = 1.2 V; T<sub>amb</sub> = 25 °C</b>							
t <sub>PHL</sub>	HIGH to LOW propagation delay	A to B	6.5	5.9	5.7	5.5	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	A to B	7.1	6.3	6.2	6.6	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	B to A	6.2	5.4	5.1	5	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	B to A	5.6	4.1	3.6	3.2	ns
t <sub>en</sub>	enable time	OE to A; B [1]	200	200	200	200	ns
t <sub>dis</sub>	disable time	OE to A; no external load [1]	12	12	12	12	ns
		OE to B; no external load [2]	12	12	12	12	ns
		OE to A; see Fig. 5	90	90	90	90	ns
		OE to B; see Fig. 5	95	75	100	75	ns
t <sub>TLH</sub>	LOW to HIGH output transition time	A port	6.5	5.2	4.8	4.4	ns
		B port	6.6	4.3	2.1	1.5	ns
t <sub>THL</sub>	HIGH to LOW output transition time	A port	5.8	4.8	4.3	3.8	ns
		B port	3.6	2.2	1.8	1.5	ns
t <sub>sk(o)</sub>	output skew time	between channels [3]	1	1	1	1	ns
t <sub>W</sub>	pulse width	data inputs	20	16.7	16.7	16.7	ns
f <sub>data</sub>	data rate		50	60	60	60	Mbps

[1] t<sub>en</sub> is the same as t<sub>pZL</sub> and t<sub>pZH</sub>; t<sub>dis</sub> is the same as t<sub>pLZ</sub> and t<sub>pHZ</sub>.

[2] These values are guaranteed by design.

[3] Skew between any two outputs of the same package switching in the same direction.



## Dual supply translating transceiver; open drain; auto direction sensing

Table 10. Dynamic characteristics for temperature range -40 °C to +85 °C

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 7; for waveforms see Fig. 4 and Fig. 6.

Symbol	Parameter	Conditions	V <sub>CC(B)</sub>								Unit
			1.8 V ± 0.15 V		2.5 V ± 0.2 V		3.3 V ± 0.3 V		5.0 V ± 0.5 V		
			Min	Max	Min	Max	Min	Max	Min	Max	
<b>V<sub>CC(A)</sub> = 1.5 V ± 0.1 V</b>											
t <sub>PHL</sub>	HIGH to LOW propagation delay	A to B	-	11	-	9.2	-	8.6	-	8.6	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	A to B	-	12.6	-	10	-	9.8	-	9.7	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	B to A	-	12.7	-	11.1	-	11	-	12	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	B to A	-	10.5	-	6.9	-	5.6	-	4.6	ns
t <sub>en</sub>	enable time	OE to A; B [1]	-	200	-	200	-	200	-	200	ns
t <sub>dis</sub>	disable time	OE to A; no external load [1]	-	17	-	17	-	17	-	17	ns
		OE to B; no external load [2]	-	18	-	17	-	17	-	17	ns
		OE to A; see Fig. 5	-	120	-	120	-	120	-	125	ns
		OE to B; see Fig. 5	-	170	-	125	-	175	-	125	ns
t <sub>TLH</sub>	LOW to HIGH output transition time	A port	2.6	13.1	2.8	9.8	2.0	9.0	2.0	8.3	ns
		B port	2.9	11.4	1.9	8.1	0.9	5.3	0.7	3	ns
t <sub>THL</sub>	HIGH to LOW output transition time	A port	2.1	9.9	1.5	7.7	1.2	6.8	0.8	6.0	ns
		B port	1.5	8.7	1.0	5.5	0.9	3.8	0.8	3.1	ns
t <sub>sk(o)</sub>	output skew time	between channels [3]	-	1	-	1	-	1.1	-	1	ns
t <sub>W</sub>	pulse width	data inputs	20	-	20	-	20	-	20	-	ns
f <sub>data</sub>	data rate		-	50	-	50	-	50	-	50	Mbps
<b>V<sub>CC(A)</sub> = 1.8 V ± 0.15 V</b>											
t <sub>PHL</sub>	HIGH to LOW propagation delay	A to B	-	9.7	-	7.3	-	6.5	-	5.9	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	A to B	-	11.3	-	8.4	-	7.4	-	6.5	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	B to A	-	9.8	-	8.0	-	7.4	-	7.0	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	B to A	-	10.2	-	7.0	-	5.8	-	5.0	ns
t <sub>en</sub>	enable time	OE to A; B [1]	-	200	-	200	-	200	-	200	ns
t <sub>dis</sub>	disable time	OE to A; no external load [1]	-	13	-	13	-	13	-	13	ns
		OE to B; no external load [2]	-	16	-	13	-	13	-	13	ns
		OE to A; see Fig. 5	-	140	-	140	-	140	-	145	ns
		OE to B; see Fig. 5	-	165	-	125	-	175	-	125	ns
t <sub>TLH</sub>	LOW to HIGH output transition time	A port	2.2	11.9	2.0	8.6	1.9	7.8	1.9	7.2	ns
		B port	2.8	12.2	1.8	7.7	1.2	5.3	0.7	2.9	ns
t <sub>THL</sub>	HIGH to LOW output transition time	A port	1.8	8.8	1.3	6.6	0.9	5.7	0.6	4.9	ns
		B port	1.3	8.3	1.0	5.4	0.9	3.9	0.7	3.0	ns
t <sub>sk(o)</sub>	output skew time	between channels [3]	-	1	-	1	-	1	-	1	ns
t <sub>W</sub>	pulse width	data inputs	22.2	-	16.7	-	16.7	-	16.7	-	ns
f <sub>data</sub>	data rate		-	45	-	60	-	60	-	60	Mbps

## Dual supply translating transceiver; open drain; auto direction sensing

Symbol	Parameter	Conditions	V <sub>CC(B)</sub>								Unit
			1.8 V ± 0.15 V		2.5 V ± 0.2 V		3.3 V ± 0.3 V		5.0 V ± 0.5 V		
			Min	Max	Min	Max	Min	Max	Min	Max	
<b>V<sub>CC(A)</sub> = 2.5 V ± 0.2 V</b>											
t <sub>PHL</sub>	HIGH to LOW propagation delay	A to B	-	-	-	6.2	-	5.3	-	4.7	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	A to B	-	-	-	6.8	-	5.9	-	5.2	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	B to A	-	-	-	5.9	-	4.8	-	4.2	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	B to A	-	-	-	6.2	-	4.6	-	3.6	ns
t <sub>en</sub>	enable time	OE to A; B [1]	-	-	-	200	-	200	-	200	ns
t <sub>dis</sub>	disable time	OE to A; no external load [1]	-	-	-	9	-	9	-	9	ns
		OE to B; no external load [2]	-	-	-	11	-	9	-	9	ns
		OE to A; see Fig. 5	-	-	-	105	-	105	-	105	ns
		OE to B; see Fig. 5	-	-	-	125	-	175	-	120	ns
t <sub>TLH</sub>	LOW to HIGH output transition time	A port	-	-	1.7	7.3	1.7	6.4	1.8	5.8	ns
		B port	-	-	1.8	7.3	1.3	5.4	0.8	3.3	ns
t <sub>THL</sub>	HIGH to LOW output transition time	A port	-	-	1.3	5.7	0.8	4.7	0.6	3.8	ns
		B port	-	-	1.1	5.4	0.9	4.1	0.7	3.0	ns
t <sub>sk(o)</sub>	output skew time	between channels [3]	-	-	-	1	-	1.2	-	1	ns
t <sub>W</sub>	pulse width	data inputs	-	-	14	-	11	-	11	-	ns
f <sub>data</sub>	data rate		-	-	-	70	-	90	-	90	Mbps

## Dual supply translating transceiver; open drain; auto direction sensing

Symbol	Parameter	Conditions	$V_{CC(B)}$								Unit
			1.8 V $\pm 0.15$ V		2.5 V $\pm 0.2$ V		3.3 V $\pm 0.3$ V		5.0 V $\pm 0.5$ V		
			Min	Max	Min	Max	Min	Max	Min	Max	
$V_{CC(A)} = 3.3$ V $\pm 0.3$ V											
$t_{PHL}$	HIGH to LOW propagation delay	A to B	-	-	-	-	-	4.9	-	4.2	ns
$t_{PLH}$	LOW to HIGH propagation delay	A to B	-	-	-	-	-	5.2	-	4.6	ns
$t_{PHL}$	HIGH to LOW propagation delay	B to A	-	-	-	-	-	4.7	-	3.8	ns
$t_{PLH}$	LOW to HIGH propagation delay	B to A	-	-	-	-	-	4.7	-	4.3	ns
$t_{en}$	enable time	OE to A; B [1]	-	-	-	-	-	200	-	200	ns
$t_{dis}$	disable time	OE to A; no external load [1]	-	-	-	-	-	8	-	8	ns
		OE to B; no external load [2]	-	-	-	-	-	8	-	8	ns
		OE to A; see Fig. 5	-	-	-	-	-	150	-	150	ns
		OE to B; see Fig. 5	-	-	-	-	-	170	-	120	ns
$t_{TLH}$	LOW to HIGH output transition time	A port	-	-	-	-	1.6	5.7	1.8	5.0	ns
		B port	-	-	-	-	1.5	5.4	0.9	3.9	ns
$t_{THL}$	HIGH to LOW output transition time	A port	-	-	-	-	1.0	4.5	0.6	3.5	ns
		B port	-	-	-	-	1.0	4.2	0.8	3.1	ns
$t_{sk(o)}$	output skew time	between channels [3]	-	-	-	-	-	1	-	1	ns
$t_W$	pulse width	data inputs	-	-	-	-	11	-	9	-	ns
$f_{data}$	data rate		-	-	-	-	-	90	-	110	Mbps

[1]  $t_{en}$  is the same as  $t_{PZL}$  and  $t_{PZH}$ ;  $t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ .

[2] These values are guaranteed by design.

[3] Skew between any two outputs of the same package switching in the same direction.

## Dual supply translating transceiver; open drain; auto direction sensing

Table 11. Dynamic characteristics for temperature range -40 °C to +125 °C

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 7; for waveforms see Fig. 4 and Fig. 6.

Symbol	Parameter	Conditions	V <sub>CC(B)</sub>								Unit
			1.8 V ± 0.15 V		2.5 V ± 0.2 V		3.3 V ± 0.3 V		5.0 V ± 0.5 V		
			Min	Max	Min	Max	Min	Max	Min	Max	
<b>V<sub>CC(A)</sub> = 1.5 V ± 0.1 V</b>											
t <sub>PHL</sub>	HIGH to LOW propagation delay	A to B	-	13.8	-	11.5	-	10.8	-	10.8	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	A to B	-	15.8	-	12.5	-	12.3	-	12.1	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	B to A	-	15.9	-	13.9	-	13.8	-	15.0	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	B to A	-	13.1	-	8.6	-	7.0	-	5.8	ns
t <sub>en</sub>	enable time	OE to A; B [1]	-	200	-	200	-	200	-	200	ns
t <sub>dis</sub>	disable time	OE to A; no external load [1]	-	18	-	18	-	18	-	18	ns
		OE to B; no external load [2]	-	19	-	18	-	18	-	18	ns
		OE to A; see Fig. 5	-	120	-	120	-	120	-	125	ns
		OE to B; see Fig. 5	-	170	-	125	-	175	-	125	ns
t <sub>TLH</sub>	LOW to HIGH output transition time	A port	2.6	16.4	2.8	12.3	2.0	11.3	2.0	10.4	ns
		B port	2.9	16.1	1.9	10.1	0.9	6.6	0.7	3.8	ns
t <sub>THL</sub>	HIGH to LOW output transition time	A port	2.1	12.4	1.5	9.6	1.2	8.5	0.8	7.5	ns
		B port	1.5	10.9	1.0	6.9	0.9	4.8	0.8	3.9	ns
t <sub>sk(o)</sub>	output skew time	between channels [3]	-	1.1	-	1.1	-	1.2	-	1.1	ns
t <sub>W</sub>	pulse width	data inputs	25	-	25	-	25	-	25	-	ns
f <sub>data</sub>	data rate		-	40	-	40	-	40	-	40	Mbps
<b>V<sub>CC(A)</sub> = 1.8 V ± 0.15 V</b>											
t <sub>PHL</sub>	HIGH to LOW propagation delay	A to B	-	12.1	-	9.1	-	8.1	-	7.4	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	A to B	-	14.1	-	10.5	-	9.3	-	8.1	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	B to A	-	12.3	-	10.0	-	9.3	-	8.8	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	B to A	-	12.8	-	8.8	-	7.3	-	6.3	ns
t <sub>en</sub>	enable time	OE to A; B [1]	-	200	-	200	-	200	-	200	ns
t <sub>dis</sub>	disable time	OE to A; no external load [1]	-	14	-	14	-	14	-	14	ns
		OE to B; no external load [2]	-	17	-	14	-	14	-	14	ns
		OE to A; see Fig. 5	-	140	-	140	-	140	-	145	ns
		OE to B; see Fig. 5	-	165	-	125	-	175	-	125	ns
t <sub>TLH</sub>	LOW to HIGH output transition time	A port	2.2	14.9	2.0	10.8	1.9	9.8	1.9	9.0	ns
		B port	2.8	15.3	1.8	9.6	1.2	6.6	0.7	3.6	ns
t <sub>THL</sub>	HIGH to LOW output transition time	A port	1.8	11.0	1.3	8.3	0.9	7.1	0.6	6.1	ns
		B port	1.3	10.4	1.0	6.8	0.9	4.9	0.7	3.8	ns
t <sub>sk(o)</sub>	output skew time	between channels [3]	-	1.1	-	1.1	-	1.1	-	1.1	ns
t <sub>W</sub>	pulse width	data inputs	25	-	20	-	20	-	20	-	ns
f <sub>data</sub>	data rate		-	40	-	50	-	50	-	50	Mbps

## Dual supply translating transceiver; open drain; auto direction sensing

Symbol	Parameter	Conditions	V <sub>CC(B)</sub>								Unit
			1.8 V ± 0.15 V		2.5 V ± 0.2 V		3.3 V ± 0.3 V		5.0 V ± 0.5 V		
			Min	Max	Min	Max	Min	Max	Min	Max	
<b>V<sub>CC(A)</sub> = 2.5 V ± 0.2 V</b>											
t <sub>PHL</sub>	HIGH to LOW propagation delay	A to B	-	-	-	7.8	-	6.6	-	5.9	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	A to B	-	-	-	8.5	-	7.4	-	6.5	ns
t <sub>PHL</sub>	HIGH to LOW propagation delay	B to A	-	-	-	7.4	-	6.0	-	5.3	ns
t <sub>PLH</sub>	LOW to HIGH propagation delay	B to A	-	-	-	7.8	-	5.8	-	4.5	ns
t <sub>en</sub>	enable time	OE to A; B [1]	-	-	-	200	-	200	-	200	ns
t <sub>dis</sub>	disable time	OE to A; no external load [1]	-	-	-	10	-	10	-	10	ns
		OE to B; no external load [2]	-	-	-	12	-	10	-	10	ns
		OE to A; see Fig. 5	-	-	-	105	-	105	-	105	ns
		OE to B; see Fig. 5	-	-	-	125	-	175	-	120	ns
t <sub>TLH</sub>	LOW to HIGH output transition time	A port	-	-	1.7	9.1	1.7	8.0	1.8	7.3	ns
		B port	-	-	1.8	9.1	1.3	6.8	0.9	4.1	ns
t <sub>THL</sub>	HIGH to LOW output transition time	A port	-	-	1.3	7.1	0.8	5.9	0.6	4.8	ns
		B port	-	-	1.1	6.8	0.9	5.1	0.7	3.8	ns
t <sub>sk(o)</sub>	output skew time	between channels [3]	-	-	-	1.1	-	1.3	-	1.1	ns
t <sub>W</sub>	pulse width	data inputs	-	-	16.7	-	12.5	-	12.5	-	ns
f <sub>data</sub>	data rate		-	-	-	60	-	80	-	80	Mbps

## Dual supply translating transceiver; open drain; auto direction sensing

Symbol	Parameter	Conditions	$V_{CC(B)}$								Unit
			1.8 V $\pm 0.15$ V		2.5 V $\pm 0.2$ V		3.3 V $\pm 0.3$ V		5.0 V $\pm 0.5$ V		
			Min	Max	Min	Max	Min	Max	Min	Max	
$V_{CC(A)} = 3.3$ V $\pm 0.3$ V											
$t_{PHL}$	HIGH to LOW propagation delay	A to B	-	-	-	-	-	6.1	-	5.3	ns
$t_{PLH}$	LOW to HIGH propagation delay	A to B	-	-	-	-	-	6.5	-	5.8	ns
$t_{PHL}$	HIGH to LOW propagation delay	B to A	-	-	-	-	-	5.9	-	4.8	ns
$t_{PLH}$	LOW to HIGH propagation delay	B to A	-	-	-	-	-	5.9	-	5.4	ns
$t_{en}$	enable time	OE to A; B [1]	-	-	-	-	-	200	-	200	ns
$t_{dis}$	disable time	OE to A; no external load [1]	-	-	-	-	-	9	-	9	ns
		OE to B; no external load [2]	-	-	-	-	-	9	-	9	ns
		OE to A; see Fig. 5	-	-	-	-	-	150	-	150	ns
		OE to B; see Fig. 5	-	-	-	-	-	170	-	120	ns
$t_{TLH}$	LOW to HIGH output transition time	A port	-	-	-	-	1.6	7.1	1.8	6.3	ns
		B port	-	-	-	-	1.5	6.8	0.9	4.9	ns
$t_{THL}$	HIGH to LOW output transition time	A port	-	-	-	-	1.0	5.6	0.7	4.4	ns
		B port	-	-	-	-	1.0	5.3	0.8	3.9	ns
$t_{sk(o)}$	output skew time	between channels [3]	-	-	-	-	-	1.1	-	1.1	ns
$t_W$	pulse width	data inputs	-	-	-	-	13	-	10	-	ns
$f_{data}$	data rate		-	-	-	-	-	80	-	100	Mbps

[1]  $t_{en}$  is the same as  $t_{PZL}$  and  $t_{PZH}$ ;  $t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ .

[2] These values are guaranteed by design.

[3] Skew between any two outputs of the same package switching in the same direction.

## Dual supply translating transceiver; open drain; auto direction sensing

Table 12. Typical power dissipation capacitance

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 7 [1] [2]

Symbol	Parameter	Conditions	V <sub>CC(A)</sub>							Unit	
			1.2 V	1.2 V	1.5 V	1.8 V	2.5 V	2.5 V	3.3 V		
			V <sub>CC(B)</sub>								
			1.8 V	5.0 V	1.8 V	1.8 V	2.5 V	5.0 V	3.3 V to 5.0 V		
<b>T<sub>amb</sub> = 25 °C</b>											
C <sub>PD</sub>	power dissipation capacitance	outputs enabled; OE = V <sub>CC(A)</sub>									
		A port: (direction A to B)	7.7	7.4	8.0	8.3	8.4	8.0	8.7	pF	
		A port: (direction B to A)	5.9	6.3	6.6	7.5	8.2	7.0	8.5	pF	
		B port: (direction A to B)	20.8	26.6	19.9	19.7	20.0	24.3	22.2	pF	
		B port: (direction B to A)	18.9	23.8	18.4	18.4	19.0	21.2	20.3	pF	
		outputs disabled; OE = GND									
		A port: (direction A to B)	0.01	0.01	0.01	0.01	0.01	0.01	0.01	pF	
		A port: (direction B to A)	0.01	0.01	0.01	0.01	0.01	0.01	0.01	pF	
		B port: (direction A to B)	0.01	0.02	0.01	0.01	0.01	0.01	0.01	pF	
		B port: (direction B to A)	0.01	0.03	0.01	0.01	0.01	0.01	0.01	pF	

[1] C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).

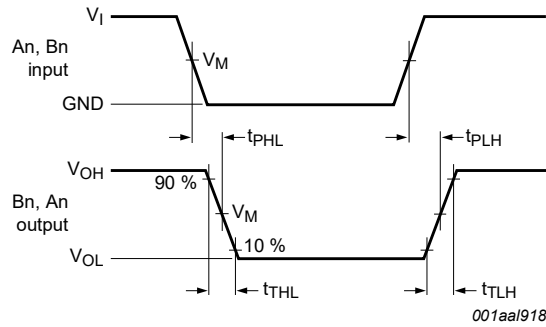
$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f<sub>i</sub> = input frequency in MHz; f<sub>o</sub> = output frequency in MHz; C<sub>L</sub> = load capacitance in pF;

V<sub>CC</sub> = supply voltage in V; N = number of inputs switching;  $\sum(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

[2] f<sub>i</sub> = 10 MHz; V<sub>I</sub> = GND to V<sub>CC</sub>; t<sub>r</sub> = t<sub>f</sub> = 1 ns; C<sub>L</sub> = 0 pF; R<sub>L</sub> = ∞ Ω.

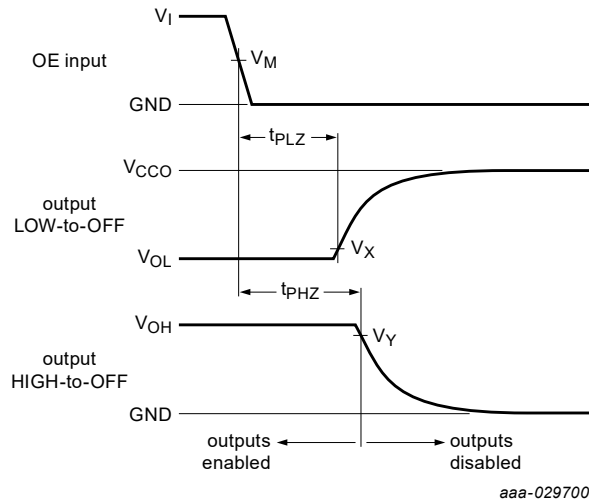
11.1. Waveforms and test circuit



Measurement points are given in [Table 13](#).

$V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

**Fig. 4. The data input (An, Bn) to data output (Bn, An) propagation delay times**



Measurement points are given in [Table 13](#).

$V_{OL}$  and  $V_{OH}$  are typical output voltage levels that occur with the output load.

$V_{CCO}$  is the supply voltage associated with the output.

**Fig. 5. Disable times**



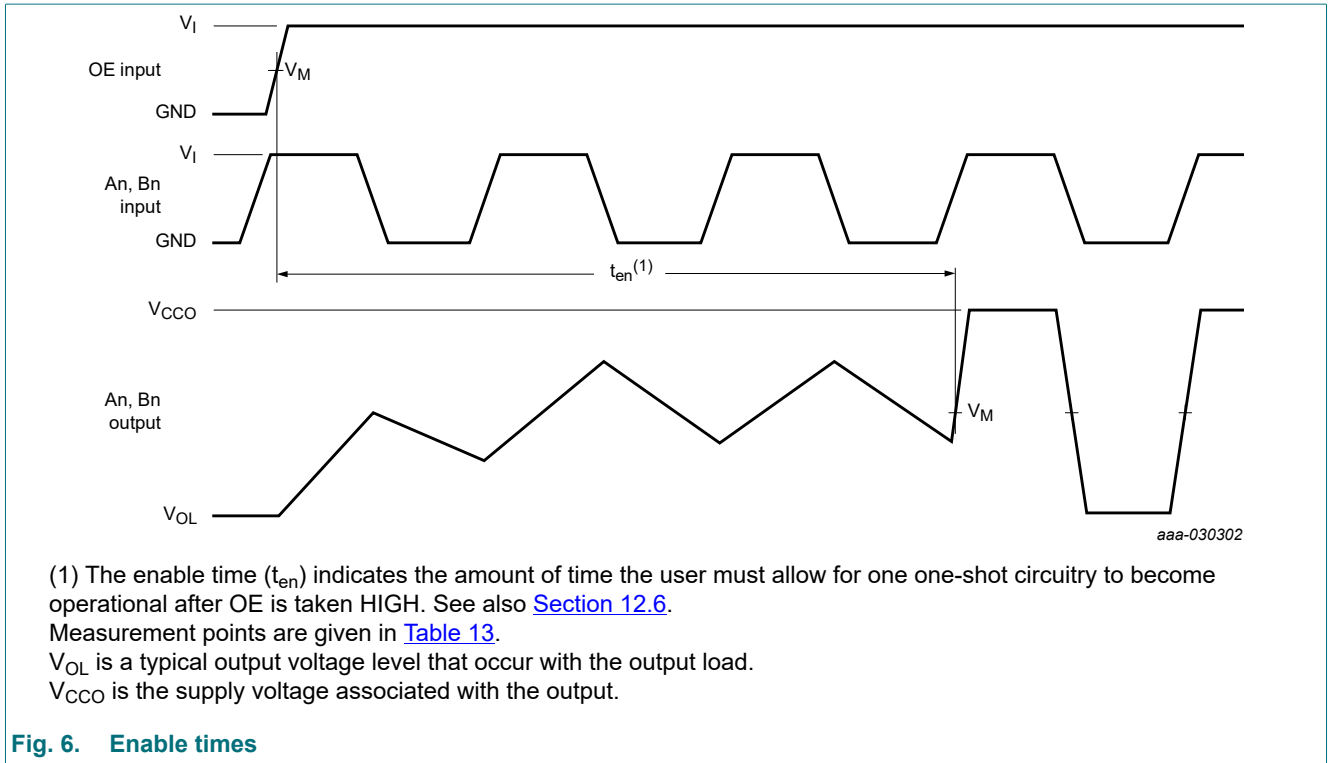


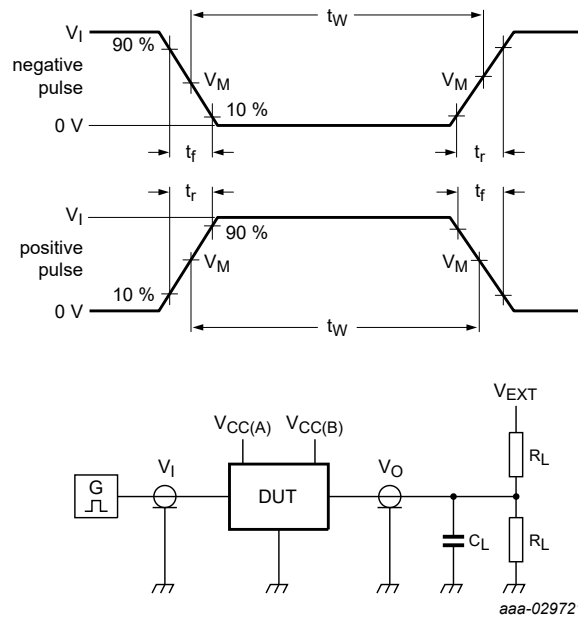
Fig. 6. Enable times

Table 13. Measurement points [1] [2]

Supply voltage	Input	Output		
$V_{CCO}$	$V_M$	$V_M$	$V_X$	$V_Y$
1.2 V	$0.5V_{CCI}$	$0.5V_{CCO}$	$V_{OL} + 0.1 V$	$V_{OH} - 0.1 V$
$1.5 V \pm 0.1 V$	$0.5V_{CCI}$	$0.5V_{CCO}$	$V_{OL} + 0.1 V$	$V_{OH} - 0.1 V$
$1.8 V \pm 0.15 V$	$0.5V_{CCI}$	$0.5V_{CCO}$	$V_{OL} + 0.15 V$	$V_{OH} - 0.15 V$
$2.5 V \pm 0.2 V$	$0.5V_{CCI}$	$0.5V_{CCO}$	$V_{OL} + 0.15 V$	$V_{OH} - 0.15 V$
$3.3 V \pm 0.3 V$	$0.5V_{CCI}$	$0.5V_{CCO}$	$V_{OL} + 0.3 V$	$V_{OH} - 0.3 V$
$5.0 V \pm 0.5 V$	$0.5V_{CCI}$	$0.5V_{CCO}$	$V_{OL} + 0.3 V$	$V_{OH} - 0.3 V$

[1]  $V_{CCI}$  is the supply voltage associated with the input.  
 [2]  $V_{CCO}$  is the supply voltage associated with the output.

Dual supply translating transceiver; open drain; auto direction sensing



Test data is given in [Table 14](#).

All input pulses are supplied by generators having the following characteristics:

PRR ≤ 10 MHz; Z<sub>O</sub> = 50 Ω; dV/dt ≥ 1.0 V/ns.

R<sub>L</sub> = Load resistance.

C<sub>L</sub> = Load capacitance including jig and probe capacitance.

V<sub>EXT</sub> = External voltage for measuring switching times.

**Fig. 7. Test circuit for measuring switching times**

**Table 14. Test data**

Supply voltage		Input		Load		V <sub>EXT</sub>		
V <sub>CC(A)</sub>	V <sub>CC(B)</sub>	V <sub>I</sub> [1]	Δt/ΔV	C <sub>L</sub>	R <sub>L</sub> [2]	t <sub>PLH</sub> , t <sub>PHL</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub> [3]
1.2 V to 3.6 V	1.65 V to 5.5 V	V <sub>CCI</sub>	≤ 1.0 ns/V	15 pF	50 kΩ, 1 MΩ	open	open	2V <sub>CCO</sub>

[1] V<sub>CCI</sub> is the supply voltage associated with the input.

[2] For measuring data rate, pulse width, propagation delay and output rise and fall measurements, R<sub>L</sub> = 1 MΩ; for measuring enable and disable times, R<sub>L</sub> = 50 kΩ.

[3] V<sub>CCO</sub> is the supply voltage associated with the output.

## 12. Application information

### 12.1. Voltage level-translation applications

The NXS0108 can be used in point-to-point applications to interface between devices or systems operating at different supply voltages. The device is primarily targeted at I<sup>2</sup>C or 1-wire which use open-drain drivers, it may also be used in applications where push-pull drivers are connected to the ports, however the NXB0108 may be more suitable.

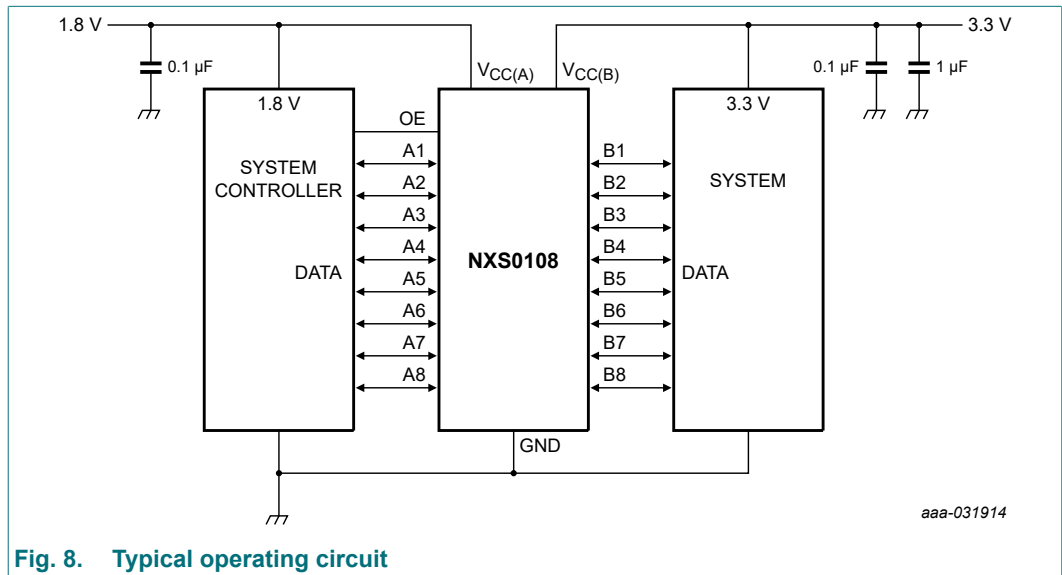


Fig. 8. Typical operating circuit

### 12.2. Architecture

The architecture of the NXS0108 is shown in Fig. 9. The device does not require an extra input signal to control the direction of data flow from A to B or B to A.

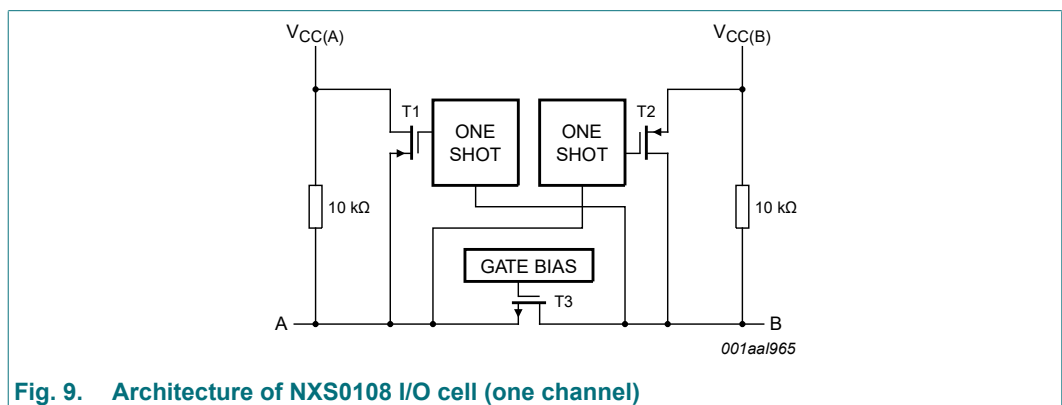


Fig. 9. Architecture of NXS0108 I/O cell (one channel)

The NXS0108 is a "switch" type voltage translator, it employs two key circuits to enable voltage translation:

1. A pass-gate transistor (N-channel) that ties the ports together.
2. An output edge-rate accelerator that detects and accelerates rising edges on the I/O pins.

The gate bias voltage of the pass gate transistor (T3) is set at approximately one threshold voltage above the  $V_{CC}$  level of the low-voltage side. During a LOW-to-HIGH transition the output one-shot accelerates the output transition by switching on the PMOS transistors (T1, T2) bypassing the 10 kΩ pull-up resistors and increasing current drive capability. The one-shot is activated once the input transition reaches approximately  $V_{CC}/2$ ; it is de-activated approximately 50 ns after the output

## Dual supply translating transceiver; open drain; auto direction sensing

reaches  $V_{CC0}/2$ . During the acceleration time the driver output resistance is between approximately  $50\ \Omega$  and  $70\ \Omega$ . To avoid signal contention and minimize dynamic  $I_{CC}$ , the user should wait for the one-shot circuit to turn-off before applying a signal in the opposite direction. Pull-up resistors are included in the device for DC current sourcing capability.

### 12.3. Input driver requirements

As the NXS0108 is a switch type translator, properties of the input driver directly effect the output signal. The external open-drain or push-pull driver applied to an I/O determines the static current sinking capability of the system; the max data rate, HIGH-to-LOW output transition time ( $t_{THL}$ ) and propagation delay ( $t_{PHL}$ ) are dependent upon the output impedance and edge-rate of the external driver. The limits provided for these parameters in the datasheet assume a driver with output impedance below  $50\ \Omega$  is used.

### 12.4. Output load considerations

The maximum lumped capacitive load that can be driven is dependant upon the one-shot pulse duration. In cases with very heavy capacitive loading there is a risk that the output will not reach the positive rail within the one-shot pulse duration. To avoid excessive capacitive loading and to ensure correct triggering of the one-shot it's recommended to use short trace lengths and low capacitance connectors on NXS0108 PCB layouts. To ensure low impedance termination and avoid output signal oscillations and one-shot re-triggering, the length of the PCB trace should be such that the round trip delay of any reflection is within the one-shot pulse duration (approximately 50 ns).

### 12.5. Power up

During operation  $V_{CC(A)}$  must never be higher than  $V_{CC(B)}$ , however during power-up  $V_{CC(A)} \geq V_{CC(B)}$  does not damage the device, so either power supply can be ramped up first. There is no special power-up sequencing required. The NXS0108 includes circuitry that disables all output ports when either  $V_{CC(A)}$  or  $V_{CC(B)}$  is switched off.

### 12.6. Enable and disable

An output enable input (OE) is used to disable the device. Setting OE = LOW causes all I/Os to assume the high-impedance OFF-state. The disable time ( $t_{dis}$  with no external load) indicates the delay between when OE goes LOW and when outputs actually become disabled. The enable time ( $t_{en}$ ) indicates the amount of time the user must allow for one one-shot circuitry to become operational after OE is taken HIGH. To ensure the high-impedance OFF-state during power-up or power-down, pin OE should be tied to GND through a pull-down resistor, the minimum value of the resistor is determined by the current-sourcing capability of the driver.

### 12.7. Pull-up or pull-down resistors on I/O lines

The NXS0108 has the pull-up resistors dynamically change value based on whether a low or a high is being passed through the I/O line. Each A-port I/O has a pull-up resistor ( $R_{PUA}$ ) to  $V_{CCA}$  and each B-port I/O has a pull-up resistor ( $R_{PUB}$ ) to  $V_{CCB}$ .  $R_{PUA}$  and  $R_{PUB}$  have a value of  $40\ k\Omega$  when the output is driving LOW.  $R_{PUA}$  and  $R_{PUB}$  have a value of  $4\ k\Omega$  when the output is driving HIGH.  $R_{PUA}$  and  $R_{PUB}$  are disabled when OE = LOW. This feature provides lower static power consumption (when the I/Os are passing a LOW) and supports lower  $V_{OL}$  values for the same size pass-gate transistor and helps improve simultaneous switching performance.

13. Package outline

TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1

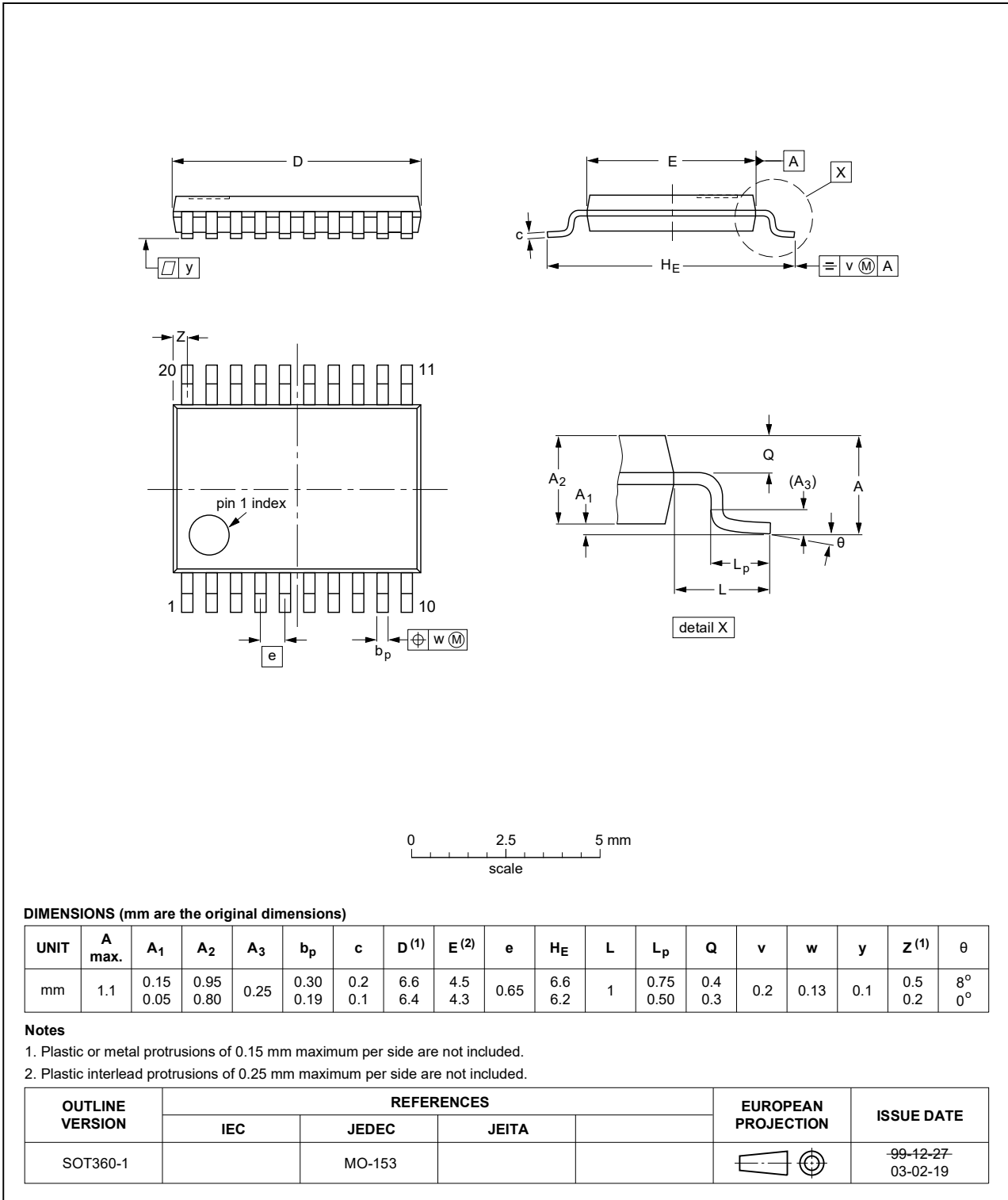


Fig. 10. Package outline SOT360-1 (TSSOP20)

Dual supply translating transceiver; open drain; auto direction sensing

DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 x 4.5 x 0.85 mm

SOT764-1



Fig. 11. Package outline SOT764-1 (DHVQFN20)

## 14. Abbreviations

**Table 15. Abbreviations**

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
I <sup>2</sup> C	Inter-Integrated Circuit
MM	Machine Model
SMBus	System Management Bus

## 15. Revision history

**Table 16. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
NXS0108 v.1	20200915	Product data sheet	-	-

## 16. Legal information

### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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